

# HV809

# **Offline High-Voltage EL Lamp Driver**

## Features

- Up to 200V DC Input Voltage
- 400V Peak-to-Peak Output Voltage
- Up to 350 nF Output Load (100 in<sup>2</sup> for 3.5 nF/in<sup>2</sup> Lamp)
- Adjustable Output Lamp Frequency
- Adjustable On/Off Pulsing Frequency

## **Applications**

- Electronic Organizers
- Handheld Portable Computers
- · Display Signs
- Portable Instrumentation Equipment

## **General Description**

The HV809 is an offline high-voltage EL lamp driver integrated circuit designed for driving EL lamps of up to 350 nF at 400 Hz. The input supply voltage can be a rectified nominal 120V AC source or any other DC source up to 200V. The HV809 supplies the EL lamp with an AC square wave with a peak-to-peak voltage of twice the input DC voltage.

The HV809 has two internal oscillators, a low-voltage output linear regulator, and a high-voltage output H-bridge. The high-voltage output H-bridge frequency is set by an external resistor connected between the REL-Osc and GND pins. The EL lamp is connected between the V<sub>A</sub> and V<sub>B</sub> pins. For the HV809 in the 8-pin package, an external RC network can be connected between the oscillator's Osc1 and Osc2 pins to pulse the EL lamp on and off.

For detailed circuit and application information, please refer to Application Note, *AN-H36*.

## Package Types



## **Functional Block Diagram**



# 1.0 ELECTRICAL CHARACTERISTICS

## Absolute Maximum Ratings†

High-Voltage Input, HV <sub>IN</sub> Internal Supply Voltage, V <sub>DD</sub>	
Maximum Junction Temperature, T <sub>JMAX</sub>	
Storage Temperature, T <sub>S</sub>	
Power Dissipation:	
8-lead SOIC	500 mW
8-lead SOIC (with Heat Slug)	1.5 Watts

**†** Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
High-Voltage Input	HV <sub>IN</sub>	50	—	200	V	
Load Capacitance	C	_	—	350	nF	R <sub>EL</sub> = 1 MΩ, HV <sub>IN</sub> = 170V
	CL	_	—	150	nF	R <sub>EL</sub> = 390 kΩ, HV <sub>IN</sub> = 170V
Operating Temperature	Τ <sub>Α</sub>	-25	—	+85	°C	

# DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: Over	recommended o	peratir	ng con	ditions (	unless	otherwise indicated; $T_A = 25^{\circ}C$
Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
High-Voltage Supply Current	-	—	_	70	mA	$HV_{IN}$ = 170V, $R_{EL}$ = 1 M $\Omega$ , CL = 350 nF
Thigh-voltage Supply Current	I <sub>IN</sub>	—		9	mA	$HV_{IN}$ = 170V, $R_{EL}$ = 1 M $\Omega$ , CL = 50 nF
Quiescent Supply Current		_		400	μA	HV <sub>IN</sub> = 170V, R <sub>EL</sub> = 1 MΩ, Osc1 = GND, No load
Quescent Supply Current	IINQ		_	100	μA	$HV_{IN}$ = 170V, $R_{EL}$ = 1 M $\Omega$ , Osc1 = $V_{DD}$ , No load
Osc2 Sink Current	I <sub>SINK</sub>	_	300	_	μA	V <sub>Osc2</sub> = 1V
Osc2 Source Current	ISOURCE	-	100	—	μA	$V_{Osc2} = V_{DD} - 1V$
Osc1 Logic Input Leakage Current	I <sub>Osc1</sub>	_	±10		μA	V <sub>Osc1</sub> = GND and V <sub>DD</sub>
Osc1 Hysteresis Voltage	V <sub>Osc1(HYST)</sub>	-	2.5	—	V	
Minimum Differential Output Voltage across Lamp	V <sub>A-B</sub>	_	_	400	V	HV <sub>IN</sub> = 200V
Internal Supply Voltage	V <sub>DD</sub>	8	10	12	V	No load on $V_{DD}$

## AC ELECTRICAL CHARACTERISTICS

Electrical Specifications:	Over recommended operating conditions unless otherwise indicated; $T_A = 25^{\circ}C$
Elooullour opoollioutiono.	

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
V <sub>A-B</sub> Output Drive Frequency	f	320	400	480	Hz	$R_{EL}$ = 1 M $\Omega$ , Osc1 = GND, C <sub>L</sub> = 350 nF
V <sub>A-B</sub> Output Drive Frequency	f <sub>EL</sub>	0.8	1	1.2	kHz	$R_{EL}$ = 390 k $\Omega$ , Osc1 = GND, $C_L$ = 150 nF
Output Rise Time	t <sub>r</sub>	_	180	250	μs	C <sub>L</sub> = 150 nF, HV <sub>IN</sub> = 170V
Output Fall Time	t <sub>f</sub>	_	50	100	μs	C <sub>L</sub> = 150 nF, HV <sub>IN</sub> = 170V

# **TEMPERATURE SPECIFICATIONS**

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	Τ <sub>Α</sub>	-25		+85	°C	
Maximum Junction Temperature	T <sub>JMAX</sub>	_	_	+125	°C	
Storage Temperature	Τ <sub>S</sub>	-55	—	+150	°C	
PACKAGE THERMAL RESISTANC	E					
8-lead SOIC	$\theta_{JA}$		101	_	°C/W	
8-lead SOIC (with Heat Slug)	$\theta_{JA}$	—	84	—	°C/W	

## 2.0 PIN DESCRIPTION

The details on the pins of HV809 8-lead SOIC (narrow body) and 8-lead SOIC (narrow body with heat slug) are listed on Table 2-1. See **Package Types** for the location of pins.

Pin Number	Pin Name	Description
1	HVIN	High-voltage input supply pin
2	VDD	Internal supply voltage
3	Osc2	The RC network can be connected between the oscillator's Osc1 and Osc2 pins to pulse the EL lamp on and off.
4	Osc1	The Output H-bridge can be enabled and disabled by connecting the Osc1 pin to the GND and VDD pins. The output can be left enabled by connecting the Osc1 pin to GND.
5	REL-Osc	EL lamp frequency is controlled via an external REL resistor connected between the REL-Osc and GND pins of the device.
6	GND	Ground pin
7	VB	VB side of the EL lamp driver H-bridge. Connection for one of the EL lamp terminals.
8	VA	VA side of the EL lamp driver H-bridge. Connection for one of the EL lamp terminals.

TABLE 2-1: PIN FUNCTION TABLE

**Note 1:** Heat slug is at ground potential.

## 3.0 FUNCTIONAL DESCRIPTION



FIGURE 3-1: Pulsing EL Lamp.



FIGURE 3-2: Push-button, Delayed Turn-off.



**FIGURE 3-3:** Typical Waveform on  $V_A$  and  $V_B$  and Differential Waveform  $V_A - V_B$ .

Inputs	Outp	uts
Osc1	V <sub>A</sub>	V <sub>B</sub>
GND	Enabled	Enabled
V <sub>DD</sub>	Disabled	Disabled

# **HV809**

#### 4.0 **PACKAGING INFORMATION**

#### Package Marking Information 4.1



Н

Ħ

Н

Legend:	XXX Y YY WW NNN @3 *	Product Code or Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC <sup>®</sup> designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	be carrie characters	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for product code or customer-specific information. Package may or e the corporate logo.

# 8-Lead SOIC (Narrow Body) Package Outline (LG/TG)

4.90x3.90mm body, 1.75mm height (max), 1.27mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

#### Note:

 This chamfer feature is optional. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbol		A	A1	A2	b	D	E	E1	e	h	L	L1	L2	θ	θ1
Dimension (mm)	MIN	1.35*	0.10	1.25	0.31	4.80*	5.80*	3.80*		0.25	0.40			<b>0</b> 0	5 <sup>0</sup>
	NOM	-	-	-	-	4.90	6.00	3.90	1.27 BSC	-	-	1.04 REF	0.25 BSC	-	-
	MAX	1.75	0.25	1.65*	0.51	5.00*	6.20*	4.00*		0.50	1.27		200	8 <sup>0</sup>	15 <sup>0</sup>

JEDEC Registration MS-012, Variation AA, Issue E, Sept. 2005. \* This dimension is not specified in the JEDEC drawing. Drawings are not to scale.

# 8-Lead SOIC (Narrow Body w/Heat Slug) Package Outline (SG) 4.90x3.90mm body, 1.70mm height (max), 1.27mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Note:

 If optional chamfer feature is not present, a Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/ identifier; an embedded metal marker; or a printed indicator.

Symbo	ol	Α	A1	A2	b	D	D1	Е	E1	E2	е	h	L	L1	L2	θ	θ1
Dimension (mm)	MIN	1.25*	0.00	1.25	0.31	4.80*	3.30 <sup>†</sup>	5.80*	3.80*	2.29†	0.25 1.27 BSC -		0.40			<b>0</b> °	5°
	NOM	-	-	-	-	4.90	-	6.00	3.90	-		-		0.25 BSC	-	-	
	MAX	1.70	0.15	1.55*	0.51	5.00*	3.81 <sup>†</sup>	6.20*	4.00*	2.79 <sup>†</sup>	200	0.50	1.27			<b>8</b> 0	15°

JEDEC Registration MS-012, Variation BA, Issue E, Sept. 2005. \* This dimension is not specified in the JEDEC drawing.

This dimension is not specified in the JEDEC drawing.
This dimension differs from the JEDEC drawing.

Drawings not to scale.

## APPENDIX A: REVISION HISTORY

## **Revision A (August 2018)**

- Converted Supertex Doc# DSFP-HV908 to Microchip DS20005630A
- Removed "Processed with HVCMOS<sup>®</sup> Technology" from the Features section
- Removed the "Output VDD Current" parameter from the DC Electrical Characteristics table
- Removed the 7-lead TO-220 package option
- Changed the quantity of the LG and SG packages from 2500/Reel to 3300/Reel
- Made minor text changes throughout the document

## **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	<u>xx</u>	- <u>x</u> - <u>x</u>	Examples:	
Device	Package Options	Environmental Media Type	a) HV809LG-G:	Offline High-Voltage EL Lamp Driver, 8-lead SOICPackage, 3300/Reel
Device:	HV809 =	Offline High-Voltage EL Lamp Driver	b) HV809SG-G:	Offline High-Voltage EL Lamp Driver, 8-lead SOIC Package (with Heat Slug), 3300/Reel
Packages:	LG =	8-lead SOIC		
	SG =	8-lead SOIC (with Heat Slug)		
Environmental:	G =	Lead (Pb)-free/RoHS-compliant Package		
Media Type:	(blank) =	3300/Reel for an LG Package		
	(blank) =	3300/Reel for an SG Package		
<u> </u>			1	

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

# QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

#### Trademarks

The Microchip name and logo, the Microchip logo, AnyRate, AVR, AVR logo, AVR Freaks, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, Heldo, JukeBlox, KeeLoq, Kleer, LANCheck, LINK MD, maXStylus, maXTouch, MediaLB, megaAVR, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, Prochip Designer, QTouch, SAM-BA, SpyNIC, SST, SST Logo, SuperFlash, tinyAVR, UNI/O, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

ClockWorks, The Embedded Control Solutions Company, EtherSynch, Hyper Speed Control, HyperLight Load, IntelliMOS, mTouch, Precision Edge, and Quiet-Wire are registered trademarks of Microchip Technology Incorporated in the U.S.A. Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet logo, memBrain, Mindi, MiWi, motorBench, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM, net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2018, Microchip Technology Incorporated, All Rights Reserved. ISBN: 978-1-5224-3381-1



# Worldwide Sales and Service

### AMERICAS

**Corporate Office** 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800

Raleigh, NC Tel: 919-844-7510

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110 Tel: 408-436-4270

Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078

### ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

China - Beijing Tel: 86-10-8569-7000 China - Chengdu

Tel: 86-28-8665-5511 China - Chongqing Tel: 86-23-8980-9588

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai Tel: 86-21-3326-8000

China - Shenyang Tel: 86-24-2334-2829

China - Shenzhen Tel: 86-755-8864-2200

China - Suzhou Tel: 86-186-6233-1526

China - Wuhan Tel: 86-27-5980-5300

China - Xian Tel: 86-29-8833-7252

China - Xiamen Tel: 86-592-2388138 China - Zhuhai

Tel: 86-756-3210040

## ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631 India - Pune

Tel: 91-20-4121-0141

Tel: 81-3-6880- 3770

Tel: 82-53-744-4301

Tel: 82-2-554-7200

Tel: 63-2-634-9065

Tel: 65-6334-8870

Taiwan - Hsin Chu Tel: 886-3-577-8366

Taiwan - Kaohsiung

Tel: 886-2-2508-8600

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

Italy - Padova Tel: 39-049-7625286

EUROPE

Austria - Wels

Tel: 43-7242-2244-39

Tel: 45-4450-2828

Fax: 45-4485-2829

Tel: 358-9-4520-820

Tel: 33-1-69-53-63-20

Fax: 33-1-69-30-90-79

Germany - Garching

Tel: 49-2129-3766400

Germany - Heilbronn

Germany - Karlsruhe

Tel: 49-721-625370

Germany - Munich

Tel: 49-89-627-144-0

Fax: 49-89-627-144-44

Germany - Rosenheim

Tel: 49-8031-354-560

Israel - Ra'anana

Italy - Milan

Tel: 972-9-744-7705

Tel: 39-0331-742611

Fax: 39-0331-466781

Tel: 49-7131-67-3636

Tel: 49-8931-9700

Germany - Haan

Finland - Espoo

France - Paris

Fax: 43-7242-2244-393

Denmark - Copenhagen

**Netherlands - Drunen** Tel: 31-416-690399 Fax: 31-416-690340

Norway - Trondheim

Tel: 48-22-3325737

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

**UK - Wokingham** Tel: 44-118-921-5800 Fax: 44-118-921-5820

Japan - Osaka Tel: 81-6-6152-7160 Japan - Tokyo

Korea - Daegu

Korea - Seoul

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila

Singapore

Tel: 886-7-213-7830

Taiwan - Taipei

Thailand - Bangkok Tel: 66-2-694-1351

Tel: 47-7289-7561 Poland - Warsaw

Romania - Bucharest

Tel: 40-21-407-87-50 Spain - Madrid